

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	4.8881	1.5265	N/A
RT2	12.6963	1.3113	N/A
RT3	12.2819	714.7374m	N/A
RT4	50.8495	963.3426m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	4.2066m	7.2472m	N/A
CT2	21.7184m	16.3460m	N/A
CT3	188.4778m	8.0088m	N/A
CT4	1.2411	529.9562u	N/A

Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION

R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	6.5649	596.3771m	N/A
RF2	16.4214	1.3870	N/A
RF3	15.4782	52.5323m	N/A
RF4	42.3825	2.4591	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	3.1971m	316.2933u	N/A
CF2	18.2266m	782.7577u	N/A
CF3	318.8143m	4.4959m	N/A
CF4	1.1858	9.2858u	N/A

Note

N/A indicates not applicable

